

IPL65R190E6AUMA1 Information


For Reference Only

Part Number [IPL65R190E6AUMA1](#)
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 4VSON
Package 4-PowerTSFN
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


IPL65R190E6AUMA1 Specifications

Manufacturer Part Number	IPL65R190E6AUMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	4-PowerTSFN
Series	CoolMOS? E6
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	20.2A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.5V @ 700µA
Gate Charge (Qg) (Max) @ Vgs	73nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1620pF @ 100V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	151W (Tc)
Rds On (Max) @ Id, Vgs	190 mOhm @ 7.3A, 10V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-VSON-4
Package / Case	4-PowerTSFN

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IPL65R190E6AUMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IPL65R190E6AUMA1 Payment Methods



IPL65R190E6AUMA1 Shipping Methods



If you have any question about IPL65R190E6AUMA1, please do not hesitate to contact us!

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